

DESCRIPTION

M54583P and M54583FP are eight-circuit collector-current-synchronized Darlington transistor arrays. The circuits are made of PNP and NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

FEATURES

- High breakdown voltage ($BV_{CEO} \geq 50V$)
- High-current driving ($I_c(max) = 400mA$)
- Active L-level input
- With input clamping diodes
- Wide operating temperature range ($T_a = -20$ to $+75^{\circ}C$)

APPLICATION

Interfaces between microcomputers and high-voltage, high-current drive systems, drives of relays and printers, and MOS-bipolar logic IC interfaces

FUNCTION

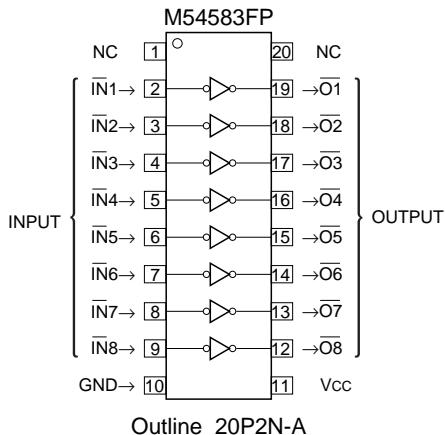
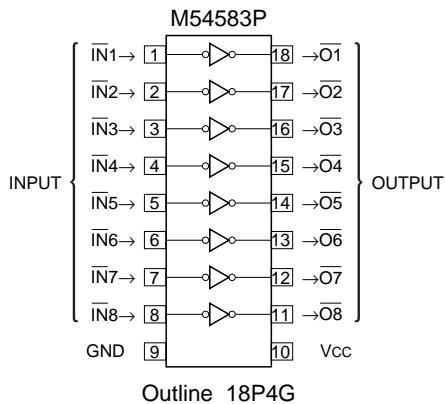
The M54583 is produced by adding PNP transistors to M54523 inputs. Eight circuits having active L-level inputs are provided.

Resistance of $7k\Omega$ and diode are provided in series between each input and PNP transistor base. The input diode is intended to prevent the flow of current from the input to the Vcc. Without this diode, the current flow from "H" input to the Vcc and the "L" input circuits is activated, in such case where one of the inputs of the 8 circuits is "H" and the others are "L" to save power consumption. The diode is inserted to prevent such misoperation.

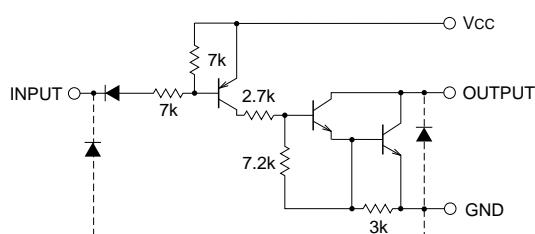
This device is most suitable for a driver using NMOS IC output especially for the driver of current sink.

Collector current is 400mA maximum. Collector-emitter supply voltage is 50V.

The 54583FP is enclosed in a molded small flat package, enabling space saving design.

PIN CONFIGURATION (TOP VIEW)

NC : No connection

CIRCUIT DIAGRAM (EACH CIRCUIT)

The eight circuits share the Vcc and GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit : Ω

POWEREX**M54583P/FP**

8-UNIT 400mA DARLINGTON TRANSISTOR ARRAY

ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted, $T_a = -20 \sim +75^\circ\text{C}$)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CC}	Supply voltage		10	V
V _{CEO}	Collector-emitter voltage	Output, H	-0.5 ~ +50	V
V _I	Input voltage		-0.5 ~ V _{CC}	V
I _C	Collector current	Current per circuit output, L	400	mA
P _d	Power dissipation	T _a = 25°C, when mounted on board	1.79/1.1	W
T _{opr}	Operating temperature		-20 ~ +75	°C
T _{stg}	Storage temperature		-55 ~ +125	°C

RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, $T_a = -20 \sim +75^\circ\text{C}$)

Symbol	Parameter	Limits			Unit
		min	typ	max	
V _{CC}	Supply voltage	4	5	8	V
I _C	Collector current Per channel	V _{CC} = 5V, Duty Cycle P : no more than 10% FP : no more than 5%	0	—	350
		V _{CC} = 5V, Duty Cycle P : no more than 34% FP : no more than 15%	0	—	200
V _{IH}	"H" input voltage	V _{CC} -0.7	—	V _{CC}	V
V _{IL}	"L" input voltage	0	—	V _{CC} -3.6	V

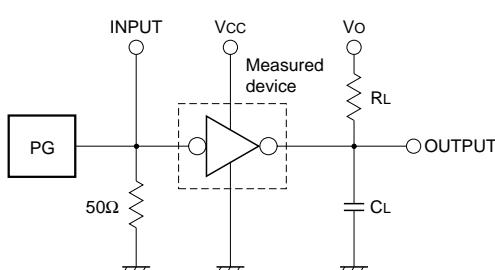
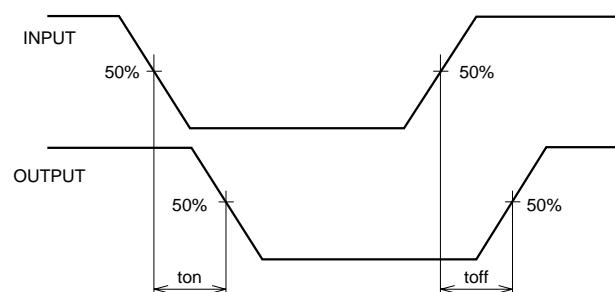
ELECTRICAL CHARACTERISTICS (Unless otherwise noted, $T_a = -20 \sim +75^\circ\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			min	typ*	max	
V (BR) CEO	Collector-emitter breakdown voltage	I _{CEO} = 100μA, V _{CC} = 8V	50	—	—	V
V _{CE} (sat)	Collector-emitter saturation voltage	V _I = V _{CC} -3.6V	I _C = 350mA	—	1.1	2.2
			I _C = 200mA	—	0.98	1.6
I _I	Input current	V _I = V _{CC} -3.6V	—	-320	-600	μA
I _{CC}	Supply current (one circuit coming on)	V _{CC} = 5V, V _I = V _{CC} -3.6V	—	—	3	mA
h _{FE}	DC amplification factor	V _{CE} = 4V, V _{CC} = 5V, I _C = 350mA, T _a = 25°C	2000	10000	—	—

* : The typical values are those measured under ambient temperature (T_a) of 25°C. There is no guarantee that these values are obtained under any conditions.

SWITCHING CHARACTERISTICS (Unless otherwise noted, T_a = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t _{on}	Turn-on time	CL = 15pF (note 1)	—	130	—	ns
t _{off}	Turn-off time	—	—	3200	—	ns

NOTE 1 TEST CIRCUIT**TIMING DIAGRAM**

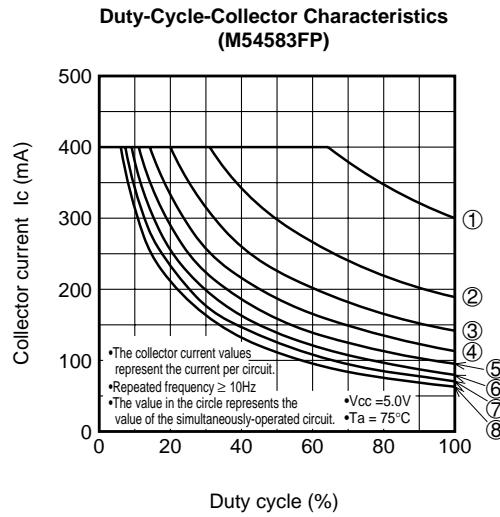
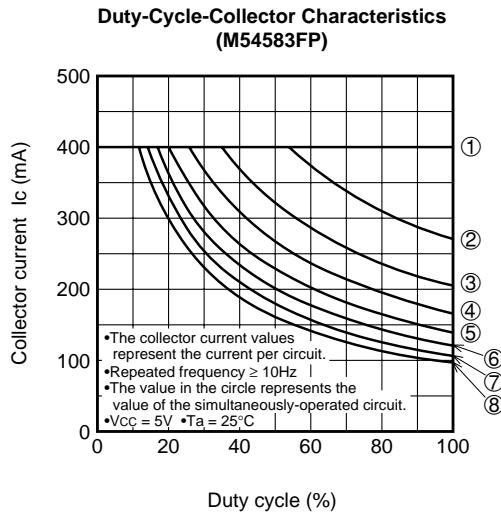
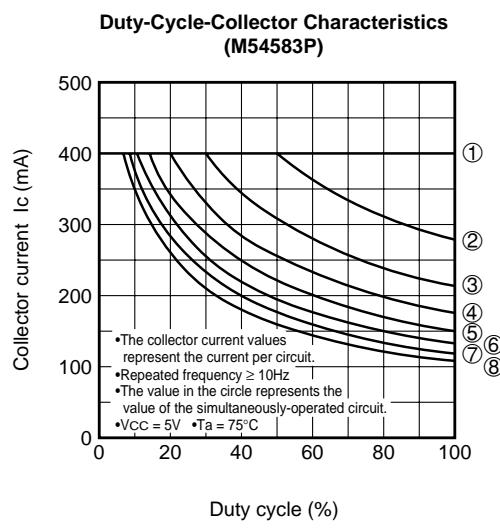
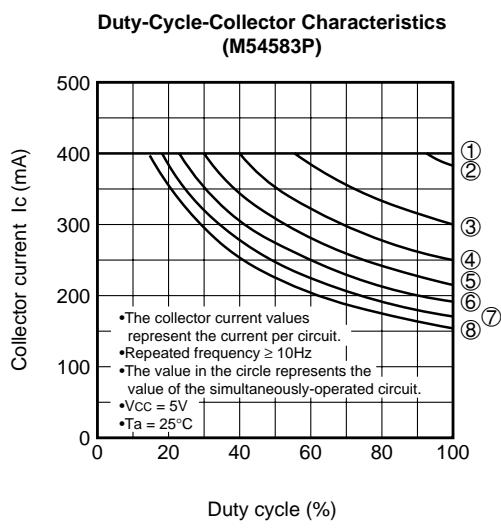
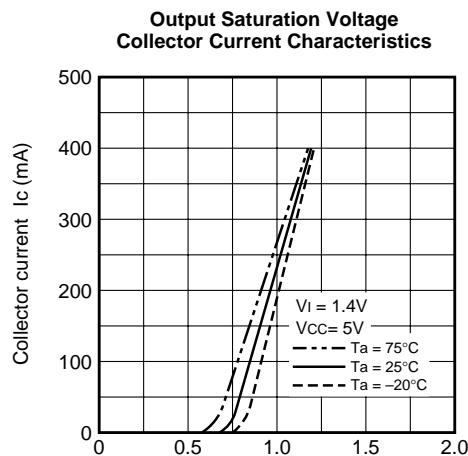
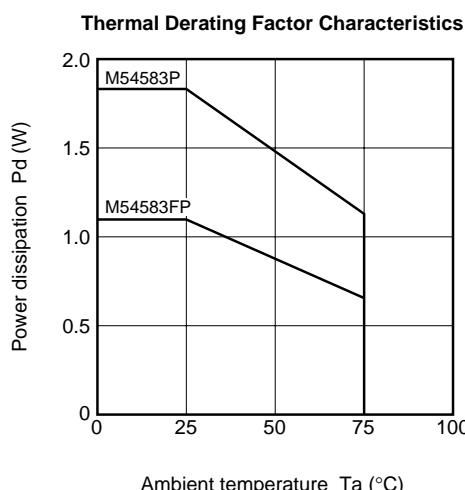
(1) Pulse generator (PG) characteristics : PRR = 1kHz,
 $t_w = 10\mu\text{s}$, $t_r = 6\text{ns}$, $t_f = 6\text{ns}$, $Z_0 = 50\Omega$
 $V_I = 0.4$ to 4V

(2) Input-output conditions : $R_L = 30\Omega$, $V_O = 10\text{V}$, $V_{CC} = 4\text{V}$
(3) Electrostatic capacity CL includes floating capacitance at connections and input capacitance at probes

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TYPICAL CHARACTERISTICS



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